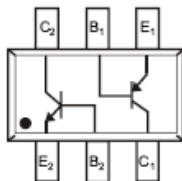


SOT-363 Plastic-Encapsulate Transistors

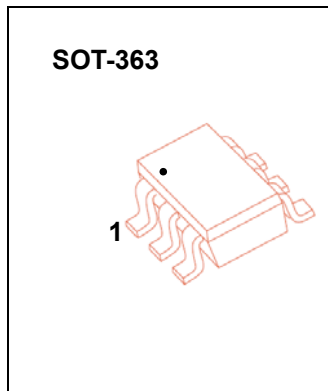
MMDT3946 COMPLEMENTARY NPN/PNP TRANSISTOR

FEATURES

- Complementary Pair
- One 3904-Type NPN
One 3906-Type PNP
- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching



E₁, B₁, C₁ = PNP3906
E₂, B₂, C₂ = NPN3904



MAKING: K46 •

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

| Symbol | Parameter | Value | Units |
|------------------|-------------------------------|---------|-------|
| V _{CB0} | Collector-Base Voltage | 60 | V |
| V _{CEO} | Collector-Emitter Voltage | 40 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current -Continuous | 0.2 | A |
| P _C | Collector Power Dissipation | 0.2 | W |
| T _J | Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature | -55-150 | °C |

NPN 3904 ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

| Parameter | Symbol | Test conditions | Min | Max | Unit |
|--------------------------------------|-----------------------|---|------|------|------|
| Collector-base breakdown voltage | V _{(BR)CBO} | I _C = 10μA, I _E =0 | 60 | | V |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | I _C = 1mA, I _B =0 | 40 | | V |
| Emitter-base breakdown voltage | V _{(BR)EBO} | I _E = 10μA, I _C =0 | 5 | | V |
| Collector cut-off current | I _{CB0} | V _{CB} = 30 V, I _E =0 | | 0.05 | μA |
| Collector cut-off current | I _{CEO} | V _{CE} = 30 V, I _B =0 | | 0.5 | μA |
| Emitter cut-off current | I _{EBO} | V _{EB} = 5 V, I _C =0 | | 0.05 | μA |
| DC current gain | h _{FE(1)} | V _{CE} = 1V, I _C = 0.1mA | 40 | | |
| | h _{FE(2)} | V _{CE} = 1V, I _C = 1mA | 70 | | |
| | h _{FE(3)} | V _{CE} = 1V, I _C = 10mA | 100 | 300 | |
| | h _{FE(4)} | V _{CE} = 1V, I _C = 50mA | 60 | | |
| | h _{FE(5)} | V _{CE} = 1V, I _C = 100mA | 30 | | |
| Collector-emitter saturation voltage | V _{CE(sat)1} | I _C =10 mA, I _B = 1mA | | 0.2 | V |
| | V _{CE(sat)2} | I _C =50 mA, I _B = 5mA | | 0.3 | V |
| Base-emitter saturation voltage | V _{BE(sat)1} | I _C = 10 mA, I _B = 1mA | 0.65 | 0.85 | V |
| | V _{BE(sat)2} | I _C = 50 mA, I _B = 5mA | | 0.95 | V |
| Transition frequency | f _T | V _{CE} =20V, I _C =20mA, f=100MHz | 300 | | MHz |
| Noise figure | NF | V _{CE} =5V, I _C =0.1mA, f=1KHz, R _g =1KΩ | | 5 | dB |
| Output capacitance | C _{ob} | V _{CB} =5V, I _E =0, f=1MHz | | 4 | pF |
| Delay time | t _d | V _{CC} =3V, V _{BE} =0.5V | | 35 | nS |
| Rise time | t _r | I _C =10mA, I _{B1} =- I _{B2} =1mA | | 35 | nS |
| Storage time | t _s | V _{CC} =3V, I _C =10mA | | 200 | nS |
| Fall time | t _f | I _{B1} =-I _{B2} = 1mA | | 50 | nS |

| MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$ unless otherwise noted) | | | |
|---|-------------------------------|---------|--------------------|
| Symbol | Parameter | Value | Units |
| V_{CBO} | Collector-Base Voltage | -40 | V |
| V_{CEO} | Collector-Emitter Voltage | -40 | V |
| V_{EBO} | Emitter-Base Voltage | -5 | V |
| I_C | Collector Current -Continuous | -0.2 | A |
| P_C | Collector Power Dissipation | 0.2 | W |
| T_J | Junction Temperature | 150 | $^{\circ}\text{C}$ |
| T_{stg} | Storage Temperature | -55-150 | $^{\circ}\text{C}$ |

PNP 3906 ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

| Parameter | Symbol | Test conditions | Min | Typ | Max | Unit |
|--------------------------------------|----------------|--|-------|-----|-------|---------------|
| Collector-base breakdown voltage | $V_{(BR)CBO}$ | $I_C=-10\mu\text{A}, I_E=0$ | -40 | | | V |
| Collector-emitter breakdown voltage | $V_{(BR)CEO}$ | $I_C=-1\text{mA}, I_B=0$ | -40 | | | V |
| Emitter-base breakdown voltage | $V_{(BR)EBO}$ | $I_E=-10\mu\text{A}, I_C=0$ | -5 | | | V |
| Collector cut-off current | I_{CBO} | $V_{CB}=-30\text{V}, I_E=0$ | | | -0.05 | μA |
| Emitter cut-off current | I_{EBO} | $V_{EB}=-5\text{V}, I_C=0$ | | | -0.05 | μA |
| DC current gain | $h_{FE(1)}$ | $V_{CE}=-1\text{V}, I_C=-0.1\text{mA}$ | 60 | | | |
| | $h_{FE(2)}$ | $V_{CE}=-1\text{V}, I_C=-1\text{mA}$ | 80 | | | |
| | $h_{FE(3)}$ | $V_{CE}=-1\text{V}, I_C=-10\text{mA}$ | 100 | | 300 | |
| | $h_{FE(4)}$ | $V_{CE}=-1\text{V}, I_C=-50\text{mA}$ | 60 | | | |
| | $h_{FE(5)}$ | $V_{CE}=-1\text{V}, I_C=-100\text{mA}$ | 30 | | | |
| Collector-emitter saturation voltage | $V_{CE(sat)1}$ | $I_C=-10\text{mA}, I_B=-1\text{mA}$ | | | -0.25 | V |
| | $V_{CE(sat)2}$ | $I_C=-50\text{mA}, I_B=-5\text{mA}$ | | | -0.4 | V |
| Base-emitter saturation voltage | $V_{BE(sat)1}$ | $I_C=-10\text{mA}, I_B=-1\text{mA}$ | -0.65 | | -0.85 | V |
| | $V_{BE(sat)2}$ | $I_C=-50\text{mA}, I_B=-5\text{mA}$ | | | -0.95 | V |
| Transition frequency | f_T | $V_{CE}=-20\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$ | 250 | | | MHz |
| Collector output capacitance | C_{ob} | $V_{CB}=-5\text{V}, I_E=0, f=1\text{MHz}$ | | | 4.5 | pF |
| Noise figure | NF | $V_{CE}=-5\text{V}, I_C=-0.1\text{mA}, f=1\text{KHz}, R_g=1\text{K}\Omega$ | | | 4 | dB |
| Delay time | t_d | $V_{CC}=-3\text{V}, V_{BE}=-0.5\text{V}$ | | | 35 | nS |
| Rise time | t_r | $I_C=-10\text{mA}, I_{B1}=-I_{B2}=-1\text{mA}$ | | | 35 | nS |
| Storage time | t_s | $V_{CC}=-3\text{V}, I_C=-10\text{mA}$ | | | 225 | nS |
| Fall time | t_f | $I_{B1}=-I_{B2}=-1\text{mA}$ | | | 75 | nS |